

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S71	197	(dielectric adj constant) with ("4.0") and (MOSFET)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 17:22
S70	6780	(dielectric adj constant) and (MOSFET)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 17:22
S73	332	S72 and (@ad<"20020516")	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 17:23
S72	861	(dielectric adj constant) with ("4.0" "4") and (MOSFET)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 17:23
S74	99	S73 and (silicid\$3 salicid\$3)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 17:24
S75	2	("6949787").PN.	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/07/14 17:29
S76	39	("20010024847" "20020030231" "4053924" "4300152" "4312113" "4485550" "4513309" "4554569" "4780429" "4942441" "5040034" "5079182" "5250834" "5323053" "5338698" "5361225" "5444302" "5663584" "5665993" "5760449" "5767557" "5801398" "5883010" "6037605" "6130750"	US_PGPUB; USPAT; USOCR	OR	ON	2008/07/14 17:32

		"6160282" "6268636" "6303479" "6323528" "6353251" "6413829" "6420742" "6486080" "6495882" "6509609" "6555879" "RE32613").PN. OR ("6949787").URPN.				
S78	12	S77 and (@ad<"20020516")	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 17:36
S77	159	(MOSFET) and ("HfO. sub."\$3) and (silicide salicid \$3) with (platinum palladium iridium)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 17:36
S79	23	("20010031562" "4080719" "4419812" "4657628" "5661043" "5693554" "5736435" "5851921" "5937315" "5989957" "6002150" "6013553" "6020024" "6060755" "6100204" "6160291" "6210999" "6278165" "6291282" "6303479" "6423619" "6555424" "6590271").PN. OR ("6894355").URPN.	US_PGPUB; USPAT; USOCR	OR	ON	2008/07/14 17:40
S80	104848	(hafnium adj oxide "HfO. sub."\$2 zirconium adj oxide "ZrO.sub."\$2 cerium adj oxide "CeO.sub.2")	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 17:47
S82	7491	(gate near2 (dielectric insulat \$5)) same (hafnium adj oxide "HfO.sub."\$2 zirconium adj oxide "ZrO. sub."\$2 cerium adj oxide "CeO.sub.2" "aluminum oxide" "Al.sub.2 O.sub.3" "titanium oxide" "TiO.sub.2" "yttrium oxide" "Y.sub.2O. sub.3" "barium strontium titanate" "BST")	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 17:48
S85	43	S84 and (@ad<"20020516")	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 17:50

S84	326	S82 and S83	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 17:50
S83	1256	(silicid\$5 salicid\$5) with (platinum "Pt" palladium "Pd" iridium "Ir") and (MOSFET metal adj oxide near3 transistor)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 17:50
S86	328	(source drain "source/drain" "S/D") with (silicid\$5 salicid \$5) with (platinum "Pt" palladium "Pd" iridium "Ir")	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 18:05
S87	124	S86 and (@ad<"20020516")	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/14 18:06
S91	32	S90 and (@ad<"20010810")	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/15 10:21
S90	326	S88 and S89	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/15 10:21
S89	1256	(silicid\$5 salicid\$5) with (platinum "Pt" palladium "Pd" iridium "Ir") and (MOSFET metal adj oxide near3 transistor)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/15 10:21
S88	7501	(gate near2 (dielectric insulat \$5)) same (hafnium adj oxide "HfO.sub."\$2 zirconium adj oxide "ZrO.sub."\$2 cerium adj oxide "CeO.sub.2" "aluminum oxide" "Al.sub.2 O.sub.3" "titanium oxide" "TiO.sub.2" "yttrium oxide" "Y.sub.2O.sub.3" "barium strontium titanate" "BST")	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/15 10:21

S94	6	S93 and (@ad< "20010810")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/15 10:22
S93	159	(MOSFET) and ("HfO. sub."\$3) and (silicide salicid \$3) with (platinum palladium iridium)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/15 10:22
S95	4	(("20050035457") or ("20060012052")).PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/07/15 12:37
L12	55	(gate near2 (dielectric insulat \$3)) near10 (oxynitride near2 stack)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/07/15 17:14

7/15/2008 7:09:46 PM

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